Xiaoyan Qiu

List of Publications by Year in descending order

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16	119	7	11
papers	citations	h-index	g-index
16	16	16	144
all docs	docs citations	times ranked	citing authors

#	Article	IF	CITATIONS
1	Highly air-stable CH3NH3PbI3 solar cells with the solution-processed NiOx hole transport layers. Vacuum, 2022, 197, 110854.	3.5	3
2	Temperature dependence of resistive switching characteristics in NiO(111) films on metal layer. Journal Physics D: Applied Physics, 2021, 54, 015101.	2.8	6
3	Improved air stability and low voltage resistive switching behaviors of NiO-buffered CH ₃ NH ₃ Pbl ₃ films prepared by a solution method. Journal Physics D: Applied Physics, 2020, 53, 075101.	2.8	2
4	Effect of deposition temperature on ultra-low voltage resistive switching behavior of Fe-doped SrTiO3 films. Applied Physics Letters, 2020, 116 , .	3.3	7
5	Study of optical rotation generated by the twisted nematic liquid crystal film: based on circular birefringence effect. Applied Optics, 2019, 58, 5301.	1.8	3
6	Circularly polarized light to study linear magneto-optics for ferrofluids: $\langle i \rangle \hat{l}_{,\varsigma} / i \rangle$ -scan technique. Measurement Science and Technology, 2018, 29, 065202.	2.6	5
7	Oleic Acid Surface Modification in the Preparation of Magnetic Nanoparticles by a Chemically Induced Transition. IEEE Transactions on Magnetics, 2018, 54, 1-7.	2.1	7
8	Visible-light enhanced charge storage characteristics of amorphous Ni-doped HfO ₂ films. Journal Physics D: Applied Physics, 2018, 51, 305105.	2.8	1
9	Preparation of magnetic nanoparticles via chemically induced transition. Nanomaterials and Nanotechnology, 2017, 7, 184798041668716.	3.0	8
10	Ultra-low voltage resistive switching of HfO2 buffered (001) epitaxial NiO films deposited on metal seed layers. Applied Physics Letters, 2017, 111, .	3.3	9
11	Preparation of Magnetic Nanoparticles via a Chemically Induced Transition: Role of Treating Solution's Temperature. Nanomaterials, 2017, 7, 220.	4.1	10
12	Charge storage and tunneling mechanism of Ni nanocrystals embedded HfOxfilm. AIP Advances, 2016, 6, 055004.	1.3	2
13	Charge storage characteristics and tunneling mechanism of amorphous Ge-doped HfOx films. Applied Physics A: Materials Science and Processing, 2016, 122, 1.	2.3	2
14	Magneto-optical effect in a system of colloidal particle having anisotropic dielectric property. Optics Communications, 2014, 316, 146-151.	2.1	13
15	Memory characteristics and tunneling mechanism of Ag nanocrystal embedded HfAlOx films on Si83Ge17/Si substrate. Thin Solid Films, 2014, 562, 674-679.	1.8	7
16	A study of modified Fe3O4 nanoparticles for the synthesis of ionic ferrofluids. Applied Surface Science, 2010, 256, 6977-6981.	6.1	34